

SANYO Semiconductors DATA SHEET

NPN Epitaxial Planar Silicon Transistors

4MN10MH — High-Frequency General-Purpose **Amplifier Applications**

Features

- High fT: fT=400MHz (typ).
- High breakdown voltage: VCEO≥200V.
- · Small reverse transfer capacitance and excellent high-frequnecy characteristic : Cre=1.4pF.
- · Complementary pair with to 4MP10MH.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		200	V
Collector-to-Emitter Voltage	VCEO		200	V
Emitter-to-Base Voltage	VEBO		4	V
Collector Current	IC		100	mA
Collector Current (Pulse)	ICP		200	mA
Collector Dissipation	PC	Mounted on a ceramic board (600mm ² X0.8mm)	400	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

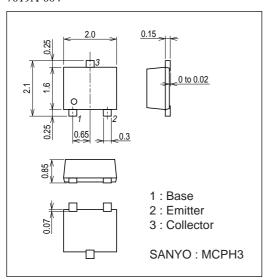
Parameter	Symbol	Conditions		Ratings		
			min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =150V, I _E =0A			0.1	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =2V, I _C =0A			1.0	μΑ
DC Current Gain	hFE1	VCE=10V, IC=10mA	60		200	
	hFE2	V _{CE} =10V, I _C =60mA	20			
Gain-Bandwideth Product	fT	V _{CE} =30V, I _C =30mA		400		MHz
Collector-to-Emitter Saturation Voltage	VCE(sat)	IC=30mA, IB=3mA			0.6	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =10μA, I _E =0A	200			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	200			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=100μA, IC=0A	4			V
Output Capacitance	Cob	V _{CB} =30V, f=1MHz		1.8		pF
Reverse Transfer Capacitance	Cre	V _{CB} =30V, f=1MHz		1.4		pF

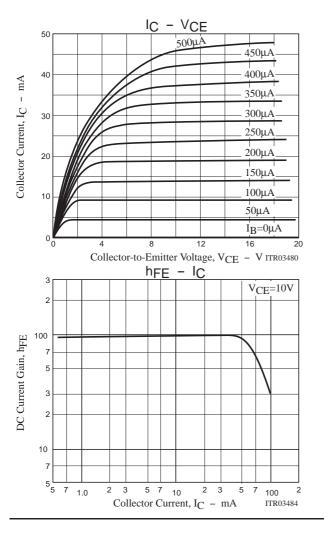
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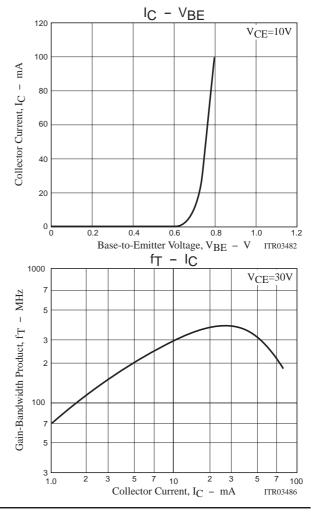
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Package Dimensions

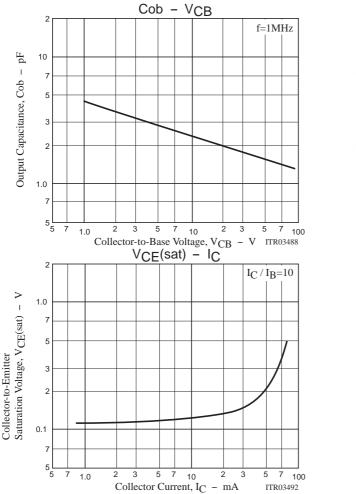
unit : mm (typ) 7019A-004

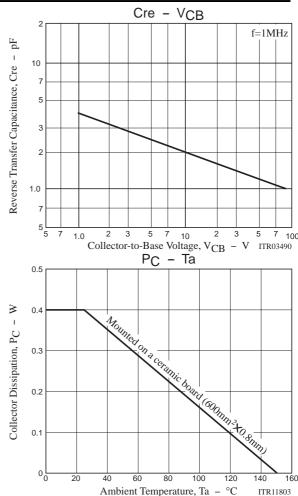






4MN10MH





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